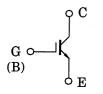
TOSHIBA IGBT Module Silicon N - Channel IGBT

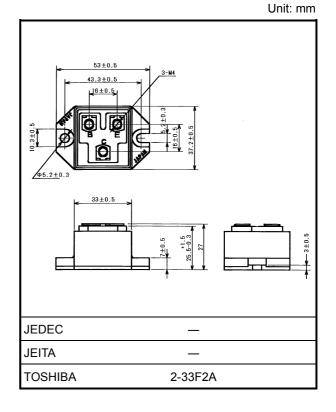
# MG25J1BS11

High Power Switching Applications Motor Control Applications

- Enhancement-mode
- The electrodes are isolated from case.

### **Equivalent Circuit**





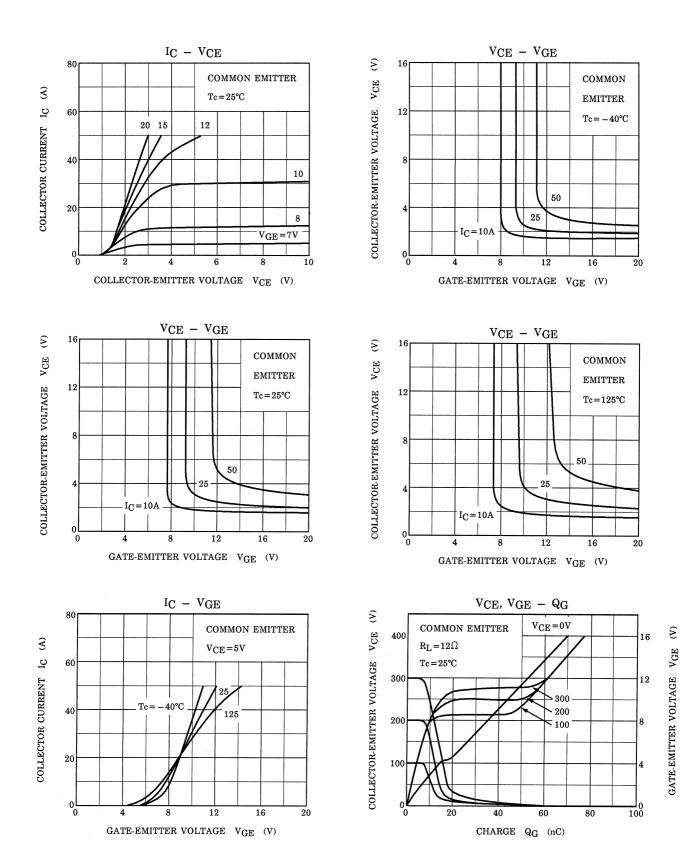
### Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Collector-emitter voltage		V <sub>CES</sub>	600	V	
Gate-emitter voltage		V <sub>GES</sub>	±20	V	
Collector current	DC	Ι <sub>C</sub>	25	A	
	1ms	I <sub>CP</sub>	50		
Collector power dissipation		P <sub>C</sub>	125	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-40 to 125	°C	
Isolation voltage		V <sub>Isol</sub>	2500 (AC 1 Minute)	V	
Screw torque (Terminal / mounting)		—	2/3	N∙m	

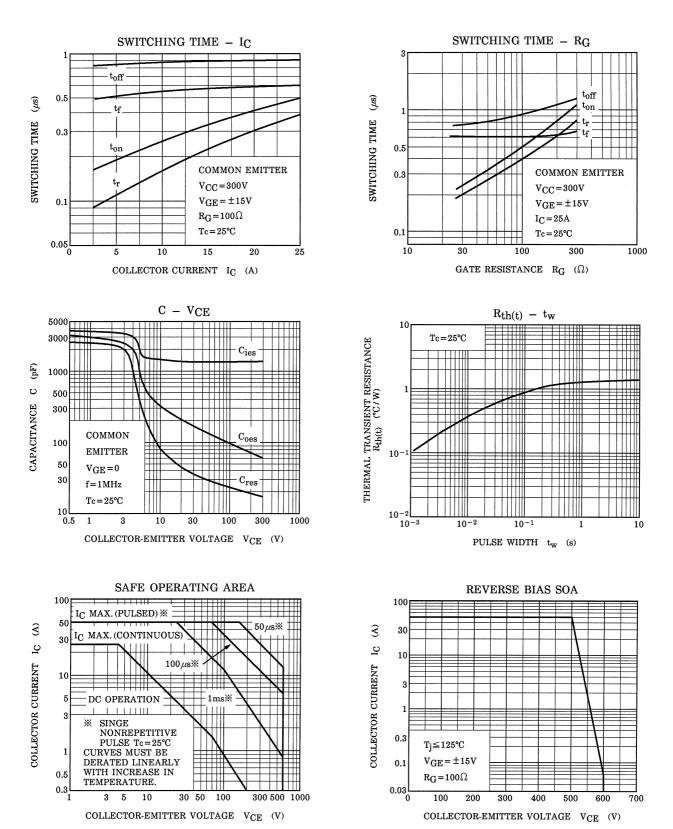
Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GES</sub>	$V_{GE}$ = ±20V, $V_{CE}$ = 0	_	_	±500	nA
Collector cut-off current		I <sub>CES</sub>	V <sub>CE</sub> = 600V, V <sub>GE</sub> = 0	_	_	1.0	mA
Gate-emitter cut-off voltage		V <sub>GE (OFF)</sub>	I <sub>C</sub> = 25mA, V <sub>CE</sub> = 5V	3.0	_	6.0	V
Collector-emitter saturation voltage		V <sub>CE (sat)</sub>	I <sub>C</sub> = 25A, V <sub>GE</sub> = 15V	_	2.3	2.7	V
Input capacitance		C <sub>ies</sub>	V <sub>CE</sub> = 10V, V <sub>GE</sub> = 0, f = 1MHz	_	1400		pF
Switching time	Rise time	t <sub>r</sub>	+15V $-15V$ $-15V$ $300V$	_	0.3	0.6	- µs
	Turn-on time	t <sub>on</sub>		_	0.4	0.8	
	Fall time	t <sub>f</sub>		_	0.6	1.0	
	Turn-off time	t <sub>off</sub>		_	1.0	1.6	
Thermal resistance		R <sub>th (j-c)</sub>	—	_	_	1.00	°C/W

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4

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